# DISCRETE SEMICONDUCTORS

# DATA SHEET

# **PMBFJ174 to 177**

P-channel silicon field-effect transistors

**Product specification** 

April 1995



#### P-channel silicon field-effect transistors

#### PMBFJ174 to 177

#### **DESCRIPTION**

Silicon symmetrical p-channel junction FETs in plastic microminiature SOT23 envelopes. They are intended for application with analogue switches, choppers, commutators etc. using SMD technology. A special feature is the interchangeability of the drain and source connections.

#### **PINNING**

1 = drain

2 = source

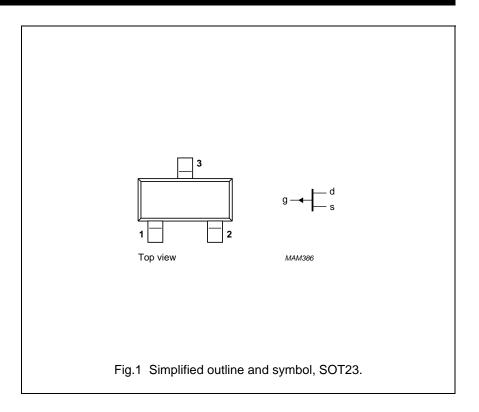
3 = gate

#### Note

1. Drain and source are interchangeable.

#### Marking codes:

174 : p6X 175 : p6W 176 : p6S 177 : p6Y



#### **QUICK REFERENCE DATA**

Drain-source voltage	± V <sub>DS</sub>	max.		30	)		٧
Gate-source voltage	$V_{GSO}$	max.		30	)		V
Gate current	$-I_{G}$	max.		50	)		mΑ
Total power dissipation							
up to T <sub>amb</sub> = 25 °C	P <sub>tot</sub>	max.		300	)		mW
Drain august		PMB	FJ174	175	176	177	
Drain current $-V_{DS} = 15 \text{ V}; V_{GS} = 0$	1	>	20	7	2	1.5	mΑ
VDS = 10 V, VGS = 0	-I <sub>DSS</sub>	<	135	70	35	20	mΑ
Drain-source ON-resistance							
$-V_{DS} = 0.1 \text{ V}; V_{GS} = 0$	$R_{DS on}$	<	85	125	250	300	Ω

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RATINGS				
Limiting values in accordance with the Absolute Maximum Syste	em (IEC 134	.)		
Drain-source voltage	$\pm  V_{DS}$	max.	30	V
Gate-source voltage	$V_{GSO}$	max.	30	V
Gate-drain voltage	$V_{GDO}$	max.	30	V
Gate current (d.c.)	$-I_{G}$	max.	50	mA
Total power dissipation				
up to $T_{amb} = 25  {}^{\circ}C^{(1)}$	$P_{tot}$	max.	300	mW
Storage temperature range	$T_{stg}$		-65  to + 150	°C
Junction temperature	$T_j$	max.	150	°C
THERMAL RESISTANCE				
From junction to ambient in free air	$R_{\text{th j-a}}$	=	430	K/W

#### STATIC CHARACTERISTICS

 $T_j = 25$  °C unless otherwise specified

•							
		PMBF	-J174	175	176	177	
Gate cut-off current							•
$V_{GS} = 20 \text{ V}; V_{DS} = 0$	$I_{GSS}$	<	1	1	1	1	nA
Drain cut-off current							
$-V_{DS} = 15 \text{ V};  V_{GS} = 10 \text{ V}$	$-I_{DSX}$	<	1	1	1	1	nA
Drain current			20	7	0	4.5	A
$-V_{DS} = 15 \text{ V}; V_{GS} = 0$	$-I_{DSS}$	> <	20 135	7 70	2 35		mA mA
			100	, ,	00	20	1117 (
Gate-source breakdown voltage							
$I_{G} = 1 \mu A; V_{DS} = 0$	$V_{(BR)GSS}$	>	30	30	30	30	V
Gate-source cut-off voltage			_	2	4	0.0	V
$-I_D = 10 \text{ nA}; V_{DS} = -15 \text{ V}$	$V_{GS \ off}$	> <	5 10	3 6	1 4	0.8 2.25	
					•	2.20	•
Drain-source ON-resistance							
$-V_{DS} = 0.1 \text{ V}; V_{GS} = 0$	$R_{DS\ on}$	<	85	125	250	300	Ω

#### Note

1. Mounted on a ceramic substrate of 8 mm  $\times$  10 mm  $\times$  0.7 mm.

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176

pF pF

рF

177

#### **DYNAMIC CHARACTERISTICS**

T<sub>i</sub> = 25 °C unless otherwise specified

Input capacitance, f = 1 MHz

Test conditions:

$V_{GS} = 10 \text{ V}; V_{DS} = 0 \text{ V}$	C <sub>is</sub>	typ.	8
$V_{GS} = V_{DS} = 0$	$C_{is}$	typ.	30

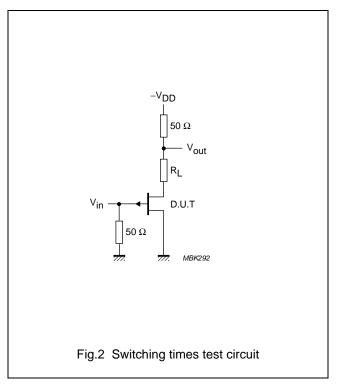
Feedback capacitance, f = 1 MHz

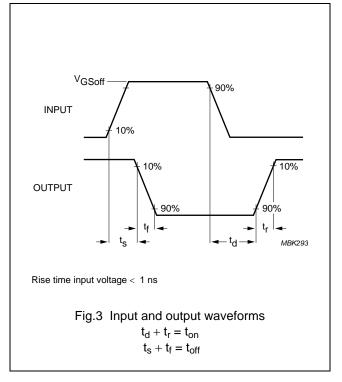
r couback capacitanics, r = r wiriz	
$V_{GS} = 10 \text{ V}; V_{DS} = 0 \text{ V}$	$C_{rs}$
Switching times (see Fig.2 + 3)	
Delay time	$t_d$
Rise time	t <sub>r</sub>
Turn-on time	$t_{on}$
Storage temperature	t <sub>s</sub>
Fall time	t <sub>f</sub>
Turn-off time	$t_{\rm off}$

$t_d$	typ.	2	5	15	20	ns
t <sub>r</sub>	typ.	5	10	20	25	ns
t <sub>on</sub>	typ.	7	15	35	45	ns
ts	typ.	5	10	15	20	ns
t <sub>f</sub>	typ.	10	20	20	25	ns
t <sub>off</sub>	typ.	15	30	35	45	ns
-V <sub>DD</sub>		10	6	6	6	V
$V_{GS off}$		12	8	6	3	V
$R_L$		560	1200	2000	2900	Ω
$V_{GS  on}$		0	0	0	0	V

typ.

PMBFJ174





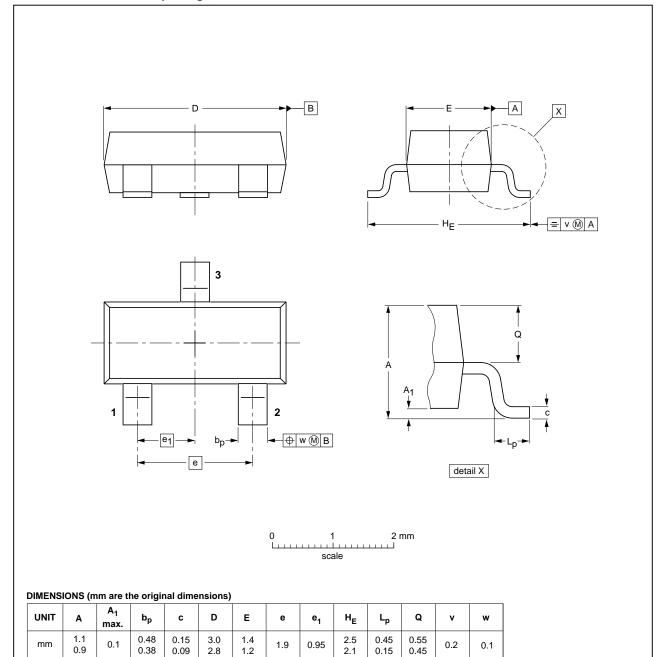
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#### **PACKAGE OUTLINE**

Plastic surface-mounted package; 3 leads

SOT23



OUTLINE	REFERENCES				EUROPEAN ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT23		TO-236AB				<del>-04-11-04-</del> 06-03-16	

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0.38

0.9

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#### **DATA SHEET STATUS**

DOCUMENT STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)</sup>	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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#### **Contact information**

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